DB2S308

Silicon epitaxial planar type

For high speed switching circuits

Features

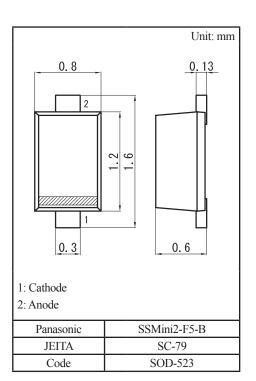
- \bullet Low forward voltage $V_{\rm F}$
- Short reverse recovery time t_{rr}
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL: Level 1 compliant)
- Marking Symbol: C2

Packaging

DB2S30800L Embossed type (Thermo-compression sealing): 3 000 pcs / reel (standard)

Absolute Maximum Ratings $T_a = 25^{\circ}C$

| 0 u | | | | |
|--|--------------------|-------------|------|--|
| Parameter | Symbol | Rating | Unit | |
| Reverse voltage | V _R | 30 | V | |
| Repetitive peak reverse voltage | V _{RRM} | 30 | V | |
| Forward current (Average) | I _{F(AV)} | 100 | mA | |
| Peak forward current | I _{FM} | 200 | mA | |
| Non-repetitive peak forward surge current *1 | I _{FSM} | 1 | А | |
| Junction temperature | Tj | 125 | °C | |
| Operating ambient temperature | T _{opr} | -40 to +85 | °C | |
| Storage temperature | T _{stg} | -55 to +125 | °C | |
| | | | | |



Note) *1: 50 Hz sine wave 1 cycle (Non-repetitive peak current)

Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

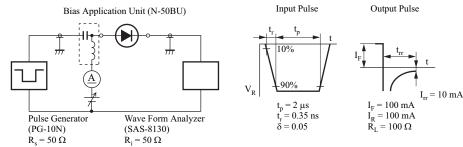
| Parameter | Symbol | Conditions | Min | Тур | Max | Unit |
|--------------------------|-----------------|--|-----|-----|------|------|
| Forward voltage | V _{F1} | $I_F = 10 \text{ mA}$ | | | 0.29 | V |
| | V _{F2} | $I_F = 100 \text{ mA}$ | | | 0.42 | |
| Reverse current | I _{R1} | $V_R = 10 V$ | | | 25 | μA |
| | I _{R2} | $V_R = 30 V$ | | | 120 | |
| Terminal capacitance | Ct | $V_{\rm R} = 10 \text{ V}, \text{ f} = 1 \text{ MHz}$ | | 2.9 | | pF |
| Reverse recovery time *1 | t _{rr} | $I_F = I_R = 100 \text{ mA}, I_{rr} = 10 \text{ mA}, R_L = 100 \Omega$ | | 1.3 | | ns |

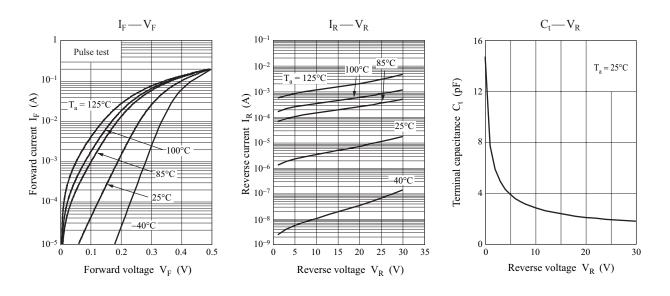
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.

2. This product is sensitive to electric shock (static electricity, etc.). Due attention must be paid on the charge of a human body and the leakage of current from the operating equipment.

3. Absolute frequency of input and output is 250 MHz

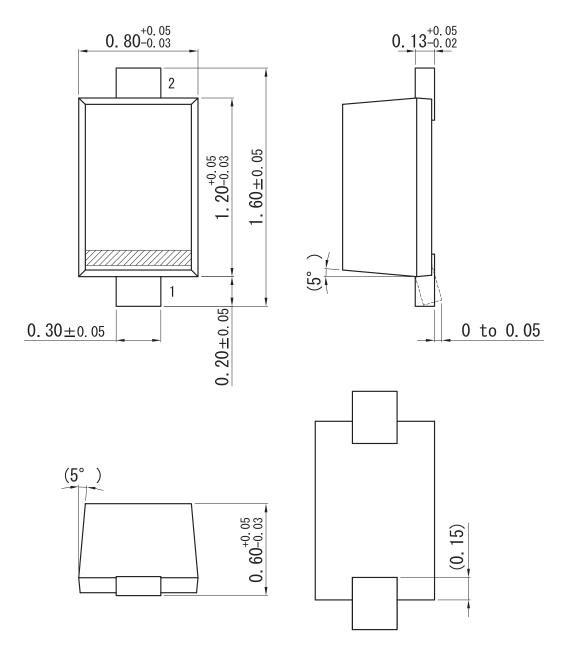
*1: trr measurement circuit



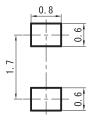


SSMini2-F5-B

Unit: mm



Land Pattern (Reference) (Unit: mm)



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